

isc N-Channel MOSFET Transistor

2SK350

DESCRIPTION

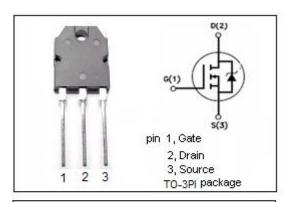
- Drain Current –I_D=10A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 450V(Min)
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

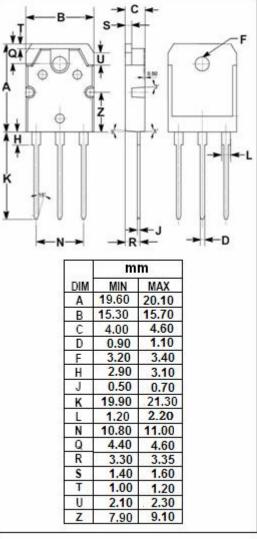
APPLICATIONS

· High speed power Switching



SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	450	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-continuous@ TC=25℃	10	Α
P _{tot}	Total Dissipation@TC=25℃	100	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C







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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	450			V
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	1.0		5.0	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = 15V; I _D = 5A		0.67	0.90	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0			±1	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =360V; V _{GS} = 0			1	mA
V _{SD}	Diode Forward Voltage	I _F = 5A; V _{GS} =0		0.85		V



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